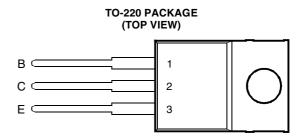


- Designed for Complementary Use with BDW63, BDW63A, BDW63B, BDW63C and BDW63D
- 60 W at 25°C Case Temperature
- 6 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 2 A



Pin 2 is in electrical contact with the mounting base.

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absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	BDW64		-45	
	BDW64A		-60	
Collector-base voltage (I _E = 0)	BDW64B	V_{CBO}	-80	V
	BDW64C		-100	
	BDW64D		-120	
	BDW64		-45	
	BDW64A		-60	
Collector-emitter voltage (I _B = 0) (see Note 1)	BDW64B	$V_{\sf CEO}$	-80	V
	BDW64C		-100	
	BDW64D		-120	
Emitter-base voltage			-5	V
Continuous collector current	I _C	-6	Α	
Continuous base current	I _B	-0.1	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P _{tot}	60	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	P _{tot}	2	W	
Unclamped inductive load energy (see Note 4)	½LI _C ²	50	mJ	
Operating junction temperature range	T _j	-65 to +150	°C	
Operating temperature range	T _{stg}	-65 to +150	°C	
Operating free-air temperature range	T _A	-65 to +150	°C	

NOTES: 1. These values apply when the base-emitter diode is open circuited.

- 2. Derate linearly to 150°C case temperature at the rate of 0.48 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = -20 V.



electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TEST	CONDITIONS		MIN	TYP	MAX	UNIT
	Collector-emitter				BDW64 BDW64A	-45 -60			
$V_{(BR)CEO}$		$I_C = -30 \text{ mA}$	$I_B = 0$	(see Note 5)	BDW64B	-80			V
					BDW64C	-100			
					BDW64D	-120			
		$V_{CE} = -30 \text{ V}$	_		BDW64			-0.5	
	Collector-emitter	$V_{CE} = -30 \text{ V}$	$I_B = 0$		BDW64A			-0.5	
I_{CEO}	cut-off current	$V_{CE} = -40 \text{ V}$	_		BDW64B			-0.5	mA
		~ —	$I_B = 0$		BDW64C			-0.5	
		$V_{CE} = -60 \text{ V}$	$I_B = 0$		BDW64D			-0.5	
		V _{CB} = -45 V	$I_E = 0$		BDW64			-0.2	
			$I_E = 0$		BDW64A			-0.2	
	Collector cut-off current	$V_{CB} = -80 \text{ V}$	$I_E = 0$		BDW64B			-0.2	
		$V_{CB} = -100 \text{ V}$	$I_E = 0$		BDW64C			-0.2	
		$V_{CB} = -120 \text{ V}$	$I_E = 0$		BDW64D			-0.2	mA
I _{CBO}		$V_{CB} = -45 \text{ V}$	$I_E = 0$	$T_C = 150^{\circ}C$	BDW64			-5	ША
		$V_{CB} = -60 \text{ V}$	$I_E = 0$	$T_C = 150^{\circ}C$	BDW64A			-5	
		$V_{CB} = -80 \text{ V}$	$I_E = 0$	$T_C = 150$ °C	BDW64B			-5	
		V _{CB} = -100 V	$I_E = 0$	T _C = 150°C	BDW64C			-5	
		$V_{CB} = -120 \text{ V}$	$I_E = 0$	T _C = 150°C	BDW64D			-5	
I _{EBO}	Emitter cut-off current	V _{EB} = -5 V	I _C = 0					-2	mA
h	Forward current	$V_{CE} = -3 \text{ V}$ $I_{C} = -2 \text{ A}$	(and Notes F and C)		750		20000		
h_{FE}	transfer ratio	V _{CE} = -3 V	$I_{C} = -6 \text{ A}$	(see Notes 5 and 6)		100			
V _{BE(on)}	Base-emitter voltage	V _{CE} = -3 V	I _C = -2 A	(see Notes 5 and 6)				-2.5	V
V	Collector-emitter	I _B = -12 mA	I _C = -2 A	(see Notes 5 and 6)				-2.5	V
V _{CE(sat)}	saturation voltage	$I_B = -60 \text{ mA}$	$I_C = -6 A$	(see Notes 5 and 6)				-4	V
V _{EC}	Parallel diode forward voltage	I _E = -6 A	I _B = 0					-3.5	V

NOTES: 5. These parameters must be measured using pulse techniques, $t_0 = 300 \mu s$, duty cycle $\leq 2\%$.

thermal characteristics

	PARAMETER			MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.08	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

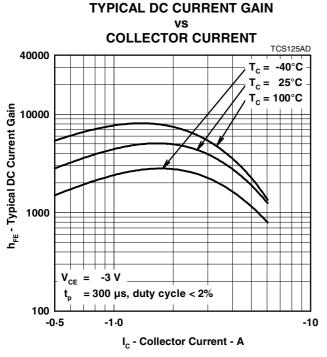
resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t _{on}	Turn-on time	I _C = -3 A	$I_{B(on)} = -12 \text{ mA}$	$I_{B(off)} = 12 \text{ mA}$		1		μs
t _{off}	Turn-off time	$V_{BE(off)} = 4.5 V$	$R_L = 10 \Omega$	$t_p = 20 \mu s, dc \le 2\%$		5		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

^{6.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS



COLLECTOR-EMITTER SATURATION VOLTAGE

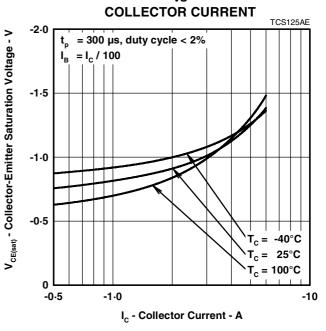
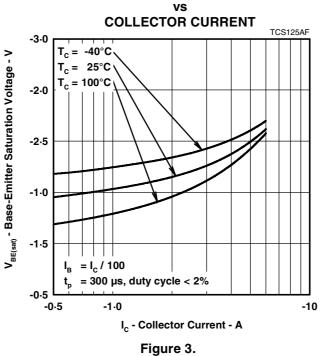


Figure 1.

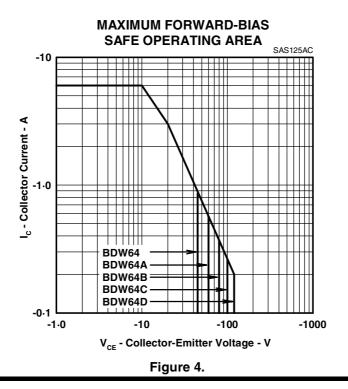
Figure 2.

BASE-EMITTER SATURATION VOLTAGE



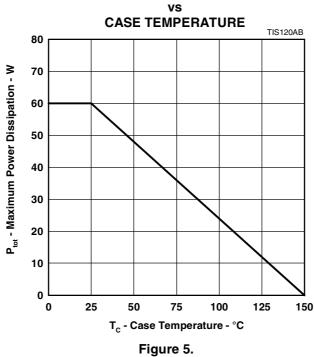
PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

MAXIMUM POWER DISSIPATION



PRODUCT INFORMATION

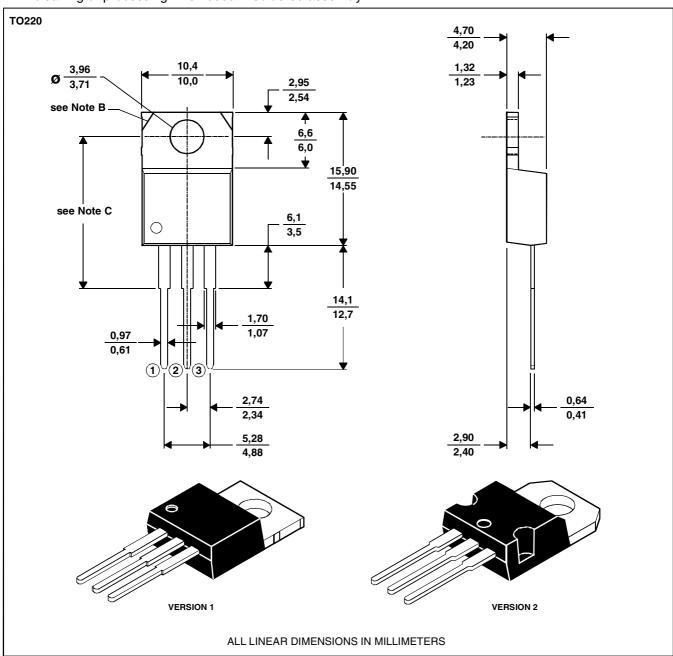


MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE